

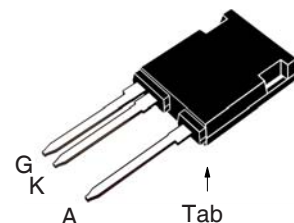
1500V MOS Gated Thyristor w/ Anti-Parallel Diode

IXHX40N150V1HV

 $V_{DM} = 1500V$ 

Symbol	Test Conditions	Maximum Ratings	
V_{DM}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	1500	V
V_{GK}	Continuous	± 30	V
V_{GK}	Transient	± 40	V
I_{TSM}	$T_C = 25^\circ\text{C}, 1\mu\text{s}$	7.6	kA
	$T_C = 25^\circ\text{C}, 10\mu\text{s}$	3.5	kA
P_D	$T_C = 25^\circ\text{C}$	695	W
T_J		-55 ... +150	$^\circ\text{C}$
T_{JM}		150	$^\circ\text{C}$
T_{stg}		-55 ... +150	$^\circ\text{C}$
T_L	Maximum Lead Temperature for Soldering	300	$^\circ\text{C}$
T_{SOLD}	1.6 mm (0.062 in.) from Case for 10s	260	$^\circ\text{C}$
F_C	Mounting Force	20..120 / 4.5..27	N/lb
Weight		6	g

TO-247PLUS-HV



G = Gate K = Cathode
A = Anode Tab = Anode

Features

- Very High Voltage Package
- Anti-Parallel Diode
- Very High Current Capability

Advantages

- High Power Density
- Low Gate Drive Requirement

Applications

- Capacitive Discharge Circuits
- Ignition Circuits
- Solid State Surge Protection

Symbol	Test Conditions ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
V_{BR}	$I_A = 250\mu\text{A}, V_{GK} = 0V$	1500		V
$V_{GK(th)}$	$I_A = 250\mu\text{A}, V_{AK} = V_{GK}$	2.5		5.0 V
V_T	$I_T = 1000A, V_{GK} = 15V$		5.95	7.5 V
r_T	$I_T > I_L, V_{GK} = 15V$		1.20	m Ω
V_{BO}	$V_{GK} = 15V$		6.45	V
I_D	$V_{AK} = 1500V, V_{GK} = 0V$ $T_J = 125^\circ\text{C}$			15 μA
				1.5 mA
I_L			250	A
I_H			200	A
I_{GKS}	$V_{AK} = 0V, V_{GK} = \pm 30V$			± 200 nA

Symbol Test Conditions

($T_J = 25^\circ\text{C}$ Unless Otherwise Specified)

Characteristic Values

Min. Typ. Max.

C_{iks}	$V_{AK} = 25\text{V}, V_{GK} = 0\text{V}, f = 1\text{MHz}$	2825	pF
C_{oks}		164	pF
C_{rks}		50	pF
$Q_{g(on)}$	$I_C = 40\text{A}, V_{GK} = 15\text{V}, V_{AK} = 600\text{V}$	99	nC
Q_{gk}		22	nC
Q_{ga}		36	nC
t_{ri}	Capacitive Discharge, $T_J = 25^\circ\text{C}$ $I_A = 2000\text{A}, V_{GK} = 15\text{V}, R_G = 1\Omega$	100	ns
t_d		50	ns
t_{ri}	Capacitive Discharge, $T_J = 125^\circ\text{C}$ $I_A = 2000\text{A}, V_{GK} = 15\text{V}, R_G = 1\Omega$	100	ns
t_d		50	ns
R_{thJC}		0.15	0.18°C/W
R_{thCS}			$^\circ\text{C/W}$

Reverse Diode (FRED)

Symbol Test Conditions

($T_J = 25^\circ\text{C}$ Unless Otherwise Specified)

Characteristic Values

Min. Typ. Max.

V_F	$I_F = 100\text{A}, V_{GK} = 0\text{V}, \text{Note 1}$		2.2 V
I_{RM}	$I_F = 50\text{A}, V_{GK} = 0\text{V},$ $-di_F/dt = 20\text{A}/\mu\text{s}, V_R = 400\text{V}$	29	A
t_{rr}		4.1	μs
R_{thJC}			0.36°C/W

Notes:

1. Pulse test, $t \leq 300\mu\text{s}$, duty cycle, $d \leq 2\%$.
2. It is recommended to use a gate driver capable of supplying more than 4Amps and $\geq 15\text{V}$ gate voltage.
3. Refer to fig. 10 & 11.

PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

TO-247PLUS-HV Outline

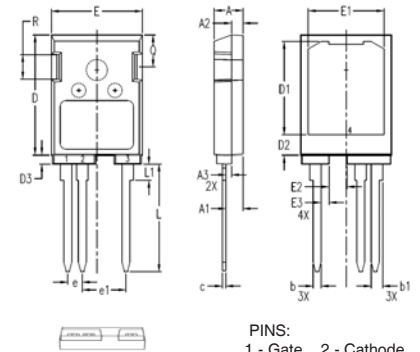


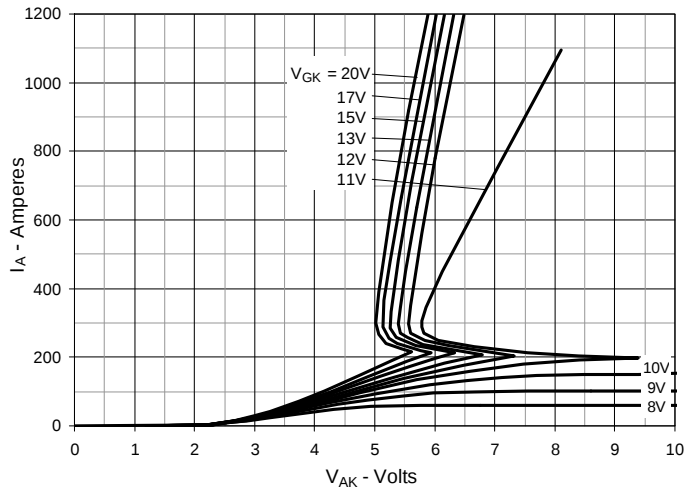
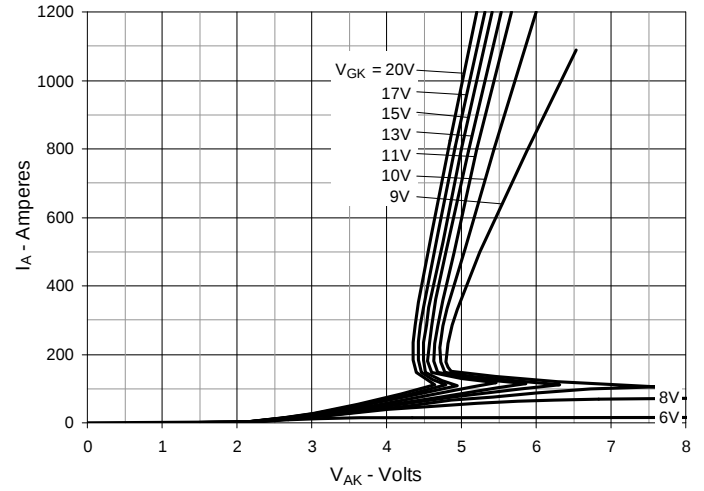
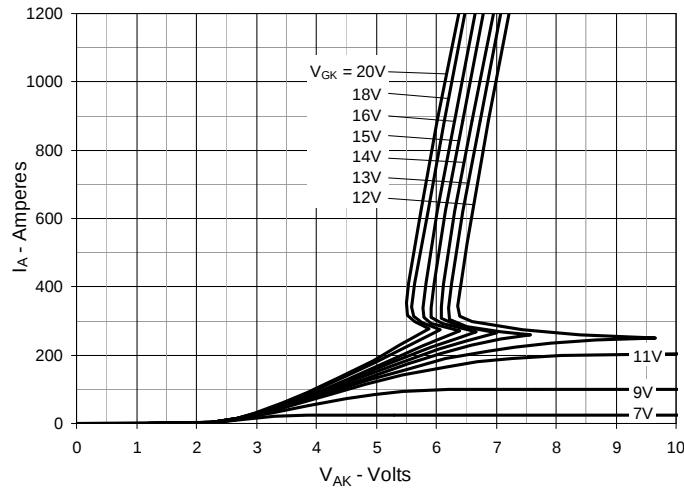
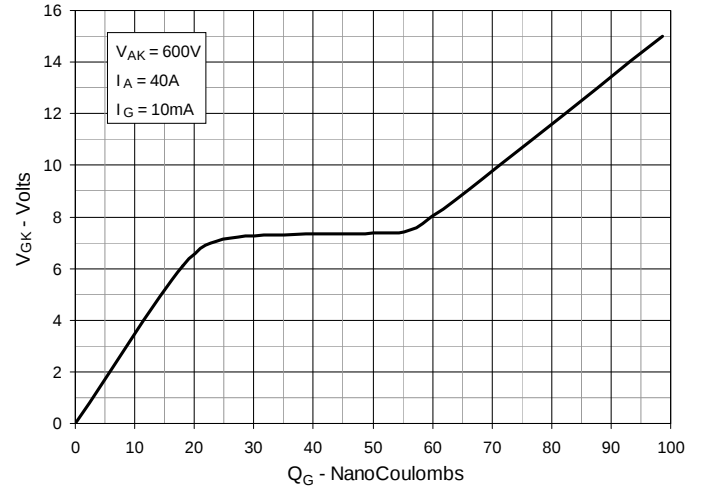
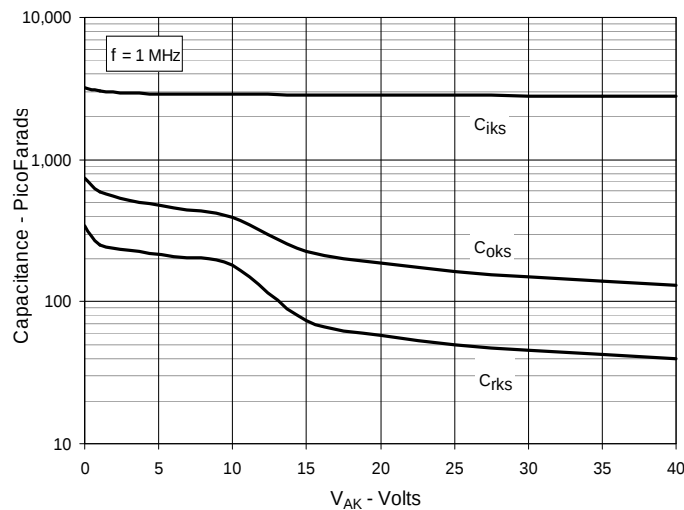
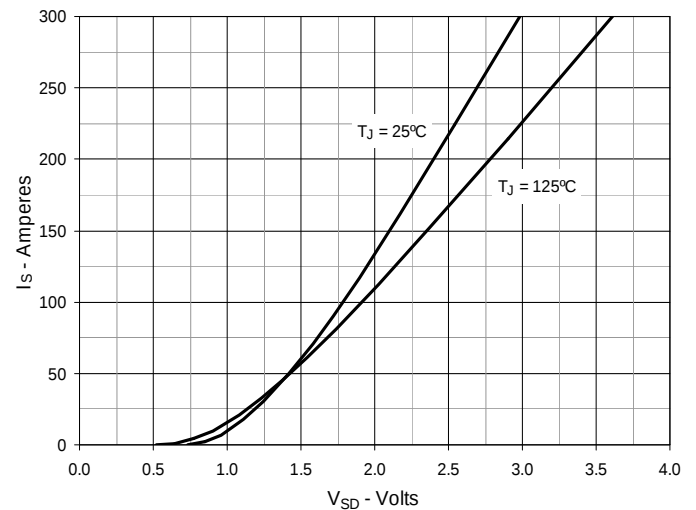
Fig. 1. Extended Output Characteristics @ $T_J = 25^\circ\text{C}$

Fig. 2. Extended Output Characteristics @ $T_J = 125^\circ\text{C}$

Fig. 3. Extended Output Characteristics @ $T_J = -40^\circ\text{C}$

Fig. 4. Gate Charge

Fig. 5. Capacitance

Fig. 6. Forward Voltage Drop of Intrinsic Diode


Fig. 7. Maximum Transient Thermal Impedance (Thyristor)

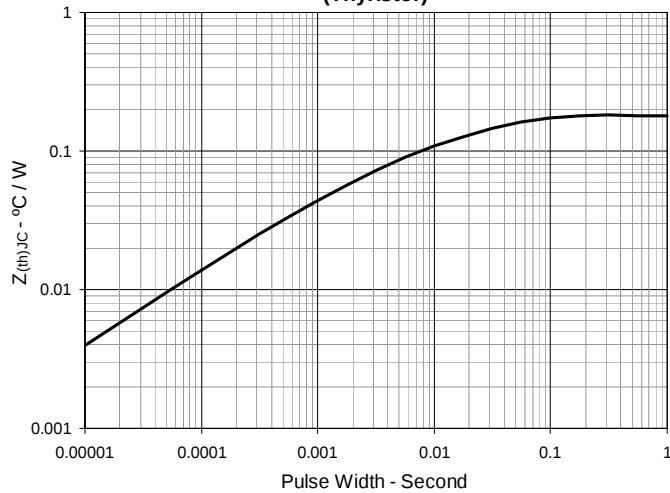


Fig. 8. Maximum Transient Thermal Impedance (Diode)

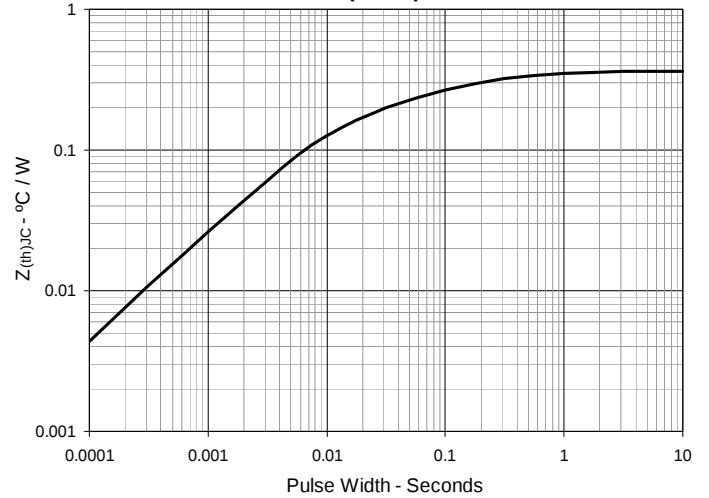
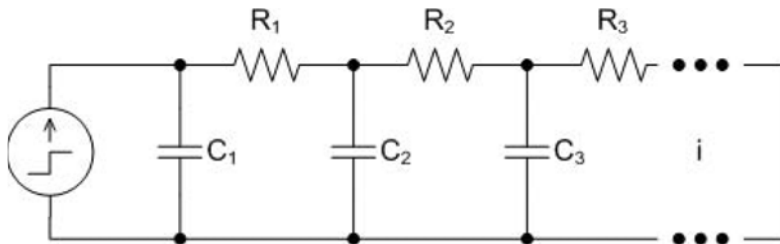


Fig. 9. Cauer Thermal Network



i	R_i (Ω)	C_i (F)
1	0.015004	0.005397
2	0.071079	0.028026
3	0.051007	0.121930
4	0.002310	2.500000

Fig. 10. Capacitive Discharge Circuit

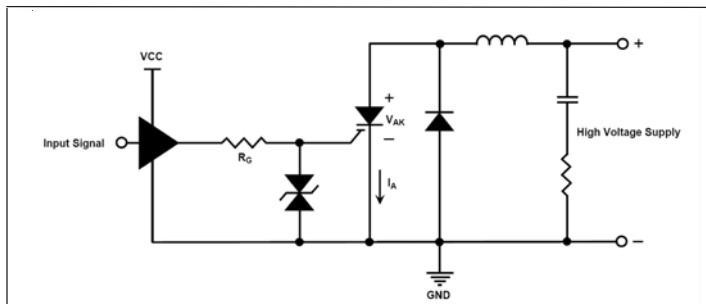
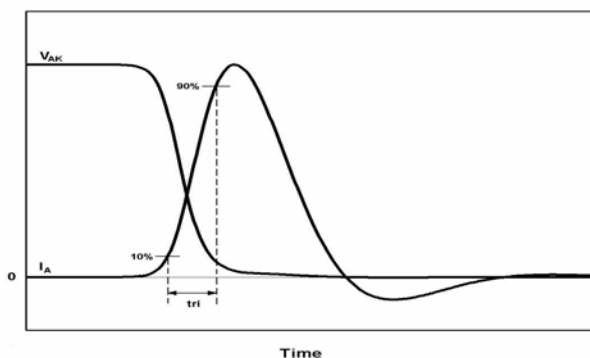


Fig. 11. Capacitive Discharge Waveform



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